



FZT705

120V PNP DARLINGTON TRANSISTOR IN SOT223

Features

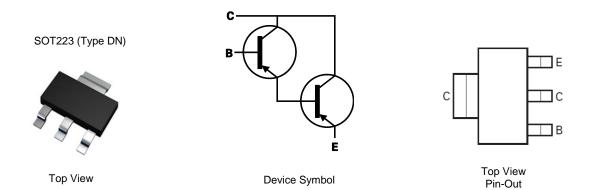
- BV_{CEO} > -120V
- BV_{CBO} > -140V
- I_C = -2A High Continuous Current
- h_{FE} > 2k for High Gain @ -2A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (FZT705Q)

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (£3)
- Weight: 0.112 grams (Approximate)

Applications

- Lamps
- Relays
- Solenoid driving



Ordering Information (Note 4)

Part Number	t Number Bookage Marking Bool Size (in		Reel Size (inches)	Tape Width (mm)	Packing	
Fart Number	Package	kage Marking Reel Size (inc				Carrier
FZT705TA	SOT223 (Type DN)	FZT705	7	12	1,000	Reel
FZT705TC	SOT223 (Type DN)	FZT705	13	12	4,000	Reel

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

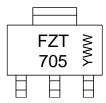
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:

SOT223 (Type DN)



 $\label{eq:FZT705} \begin{array}{l} \mathsf{FZT705} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \\ \mathsf{YWW} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \mathsf{Y} \ \mathsf{or} \ \overline{\mathsf{Y}} = \mathsf{Last} \ \mathsf{Digit} \ \mathsf{of} \ \mathsf{Year} \ (\mathsf{ex:} \ 2 = 2022) \\ \mathsf{WW} \ \mathsf{or} \ \overline{\mathsf{WW}} = \mathsf{Week} \ \mathsf{Code} \ (01 \ \mathsf{to} \ 53) \end{array}$



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-140	V
Collector-Emitter Voltage	V _{CEO}	-120	V
Emitter-Base Voltage	Vebo	-12	V
Continuous Collector Current	Ic	-2	A
Peak Pulse Current	I _{CM}	-4	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		3	
Dower Discipation	(Note 6)	D-	2	W
Power Dissipation	(Note 7)	PD	1.6	vv
	(Note 8)		1.2	
	(Note 5)		41.7	
Thermal Desistance, Junction to Ambient	(Note 6)	R _{0JA}	62.5	
Thermal Resistance, Junction to Ambient	(Note 7)		78.1	°C/W
	(Note 8)		104	
Thermal Resistance Junction to Lead	(Note 9)	Rejl	12.9	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge – Machine Model	ESD MM	≥ 200	V	В

Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

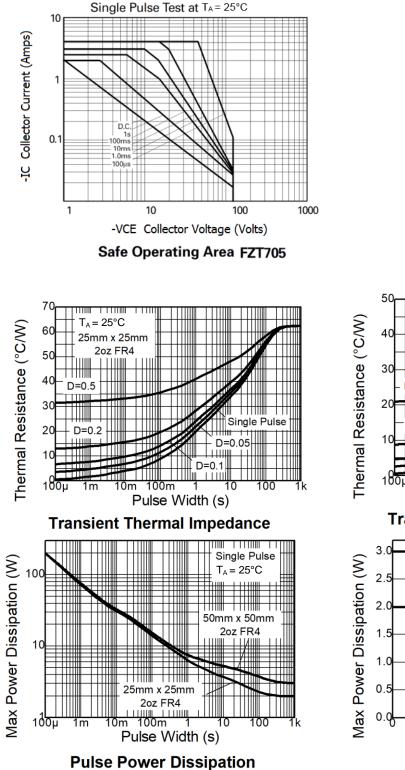
8. Same as Note 5, except the device is mounted on minimum recommended pad layout.

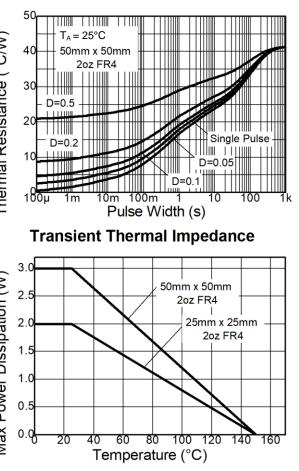
9. Thermal resistance from junction to solder-point (at the end of the collector lead).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Derating Curve

FZT705



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

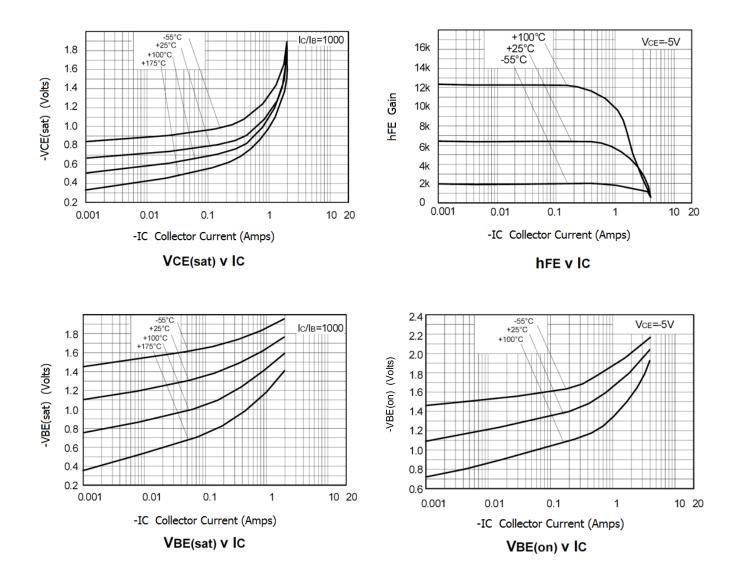
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-140	-170	_	V	$I_{c} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-120	-140	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	ВVево	-12	-16.4	_	V	I _E = -100μA
		_	-2	-100	nA	V _{CB} = -120V
Collector-Base Cut-Off Current	I _{CBO}		_	-10	μA	V _{CB} = -120V, T _A = +100°C
Collector-Emitter Cut-Off Current	ICES		-0.2	-10	μA	V _{CE} = -80V
Emitter Cut-Off Current	I _{EBO}	_	_	-50	nA	V _{EB} = -10V
	_	3k	12k	—	_	Ic = -10mA, Vce = -5V
		3k	12k	_		Ic = -100mA, VcE = -5V
DC Current Gain (Note 11)	hfe	3k	10k	30k		Ic = -1A, Vce = -5V
		2k	7k	—		Ic = -2A, Vce = -5V
	V _{CE(sat)}		-0.97	-1.3	v	Ic = -1A, I _B = -1mA
Collector-Emitter Saturation Voltage (Note 11)		_	-1.3	-2.5	v	Ic = -2A, I _B = -2mA
Base-Emitter Saturation Voltage (Note 11)	VBE(sat)	_	-1.67	-1.8	V	Ic = -1A, I _B = -10mA
Base-Emitter Turn-On Voltage (Note 11)	VBE(on)	_	-1.53	-1.7	V	Ic = -1A, Vce = -5V
Output Capacitance	Cobo	_	15	_	pF	V _{EB} = -10V, f = 1MHz
Current Gain-Bandwidth Product	f⊤	_	160	_	MHz	V _{CE} = -10V, I _C = -100mA, f = 20MHz
Turn-On Time	ton		0.6	_	μs	Vcc = -10V, Ic = -500mA,
Turn-Off Time	toff	_	0.8	_	μs	I _{B1} = -I _{B2} = -0.5mA

Note: 11. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



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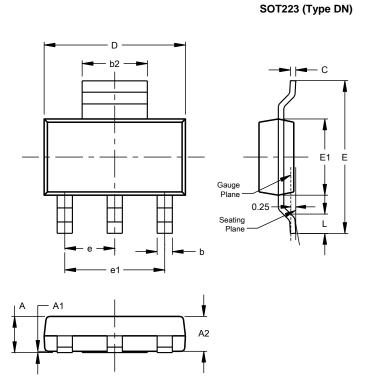
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

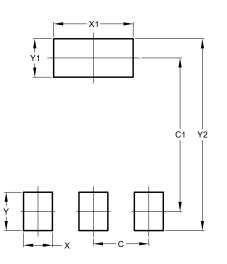
Please see http://www.diodes.com/package-outlines.html for the latest version.



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SOT223 (Type DN)						
Dim	Min	Max	Тур			
Α		1.70				
A1	0.01	0.15				
A2	1.50	1.68	1.60			
b	0.60	0.80	0.70			
b2	2.90	3.10				
С	0.20	0.32				
D	6.30	6.70				
Е	6.70	7.30				
E1	3.30	3.70				
е			2.30			
e1			4.60			
L	0.85					
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

SOT223 (Type DN)

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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